



New Product

CGP30 and DGP30

Vishay Semiconductors
formerly General Semiconductor

Clamper/Damper Glass Passivated Rectifier

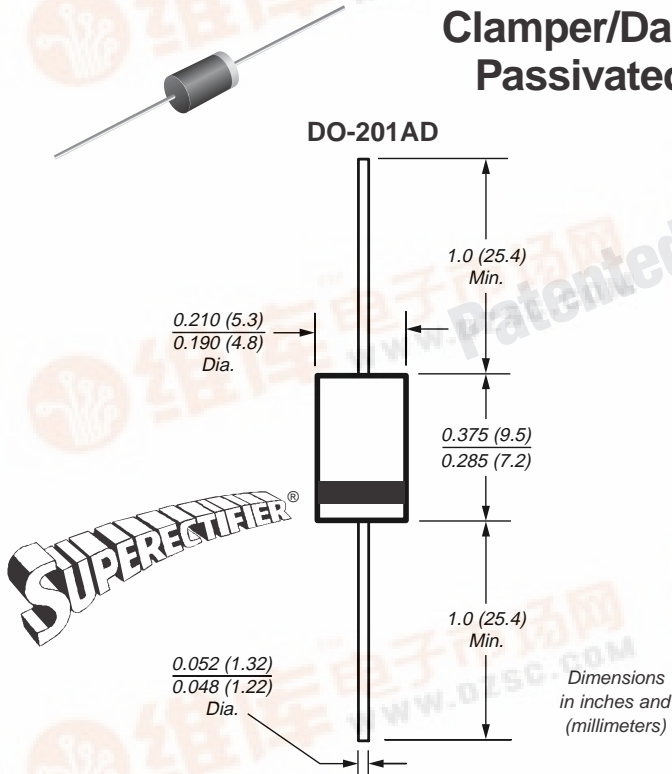
Reverse Voltage 1400 to 1500V
Forward Current 3.0A

Features

- Specially designed for clamping circuits, horizontal deflection systems and damper applications
- Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- High temperature metallurgically bonded construction
- Cavity-free glass passivated junction
- 3.0 ampere operation at $T_A=50^\circ\text{C}$ with no thermal runaway
- Typical I_R less than $0.1\mu\text{A}$
- Capable of meeting environmental standards of MIL-S-19500
- High temperature soldering guaranteed: $350^\circ\text{C}/10$ seconds, $0.375"$ (9.5mm) lead length, 5 lbs. (2.3kg) tension

Mechanical Data

Case: JEDEC DO-201AD, molded plastic over glass body
Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight: 0.04 oz., 1.12 g
Packaging codes/options:
 1/Bulk - 1.5K per container, 15K per box
 4/1.4K per 13" reel, 5.6K per box
 23/1K per ammo mag., 9K per box



* Glass-plastic encapsulation technique is covered by Patent No. 3,996,602 and brazed-lead assembly by Patent No. 3,930,306

Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

| Parameter | Symbol | CGP30 | DGP30 | Unit |
|--|-----------------|-------------|-------|---------------------------|
| Maximum repetitive peak reverse voltage | V_{RRM} | 1400 | 1500 | V |
| Maximum RMS voltage | V_{RMS} | 980 | 1050 | V |
| Maximum DC blocking voltage | V_{DC} | 1400 | 1500 | V |
| Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_A = 50^\circ\text{C}$ | $I_{F(AV)}$ | 3.0 | | A |
| Peak forward surge current 8.3ms single half sine wave superimposed on rated load (JEDEC Method) at $T_A = 50^\circ\text{C}$ | I_{FSM} | 100 | | A |
| Maximum full load reverse current full cycle average 0.375" (9.5mm) lead length at $T_A = 70^\circ\text{C}$ | $I_{R(AV)}$ | 200 | | μA |
| Typical thermal resistance (Note 1) | $R_{\theta JA}$ | 20 | | $^\circ\text{C}/\text{W}$ |
| Operating junction and storage temperature range | T_J, T_{STG} | -65 to +175 | | $^\circ\text{C}$ |

Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

| Parameter | Symbol | CGP30 | DGP30 | Unit |
|---|----------|------------|-------|---------------|
| Maximum instantaneous forward voltage at 3.0A | V_F | 1.2 | | V |
| Maximum DC reverse current $T_A = 25^\circ\text{C}$ at rated DC blocking voltage $T_A = 100^\circ\text{C}$ | I_R | 5.0 100 | | μA |
| Maximum reverse recovery time at $I_F = 0.5\text{A}, I_R = 50\text{mA}$ | t_{rr} | 15 | 20 | μs |
| Maximum reverse recovery time at $I_F=0.5\text{A}, I_R=1.0\text{A}, I_{rr}=0.25\text{A}$ typical maximum | t_{rr} | 1.0 2.0 | | μs |
| Typical junction capacitance at 4.0V, 1MHz | C_J | 40 | | pF |

Note: (1) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, with leads attached to heat sink

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Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 – Forward Current Derating Curve

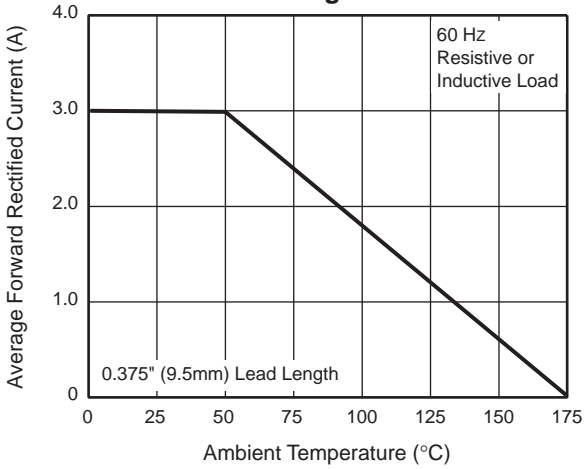


Fig. 2 – Maximum Non-Repetitive Peak Forward Surge Current

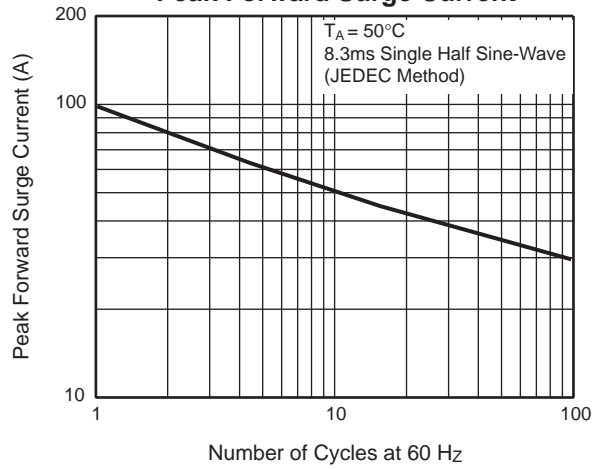


Fig. 3 – Typical Instantaneous Forward Characteristics

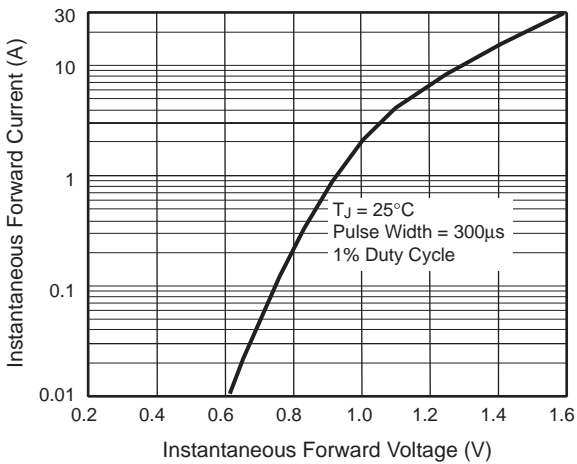


Fig. 4 – Typical Reverse Characteristics

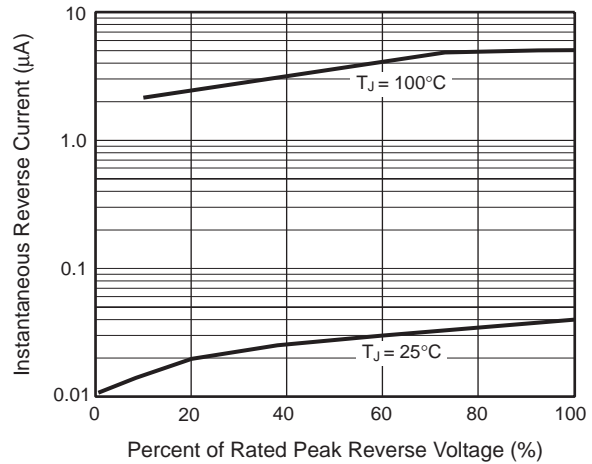


Fig. 5 – Typical Junction Capacitance

